TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

## TC7W53FU, TC7W53FK

#### 2-Channel Multiplexer/Demultiplexer

The TC7W53 is a high speed C<sup>2</sup>MOS Analog Multiplexer/ Demultiplexer fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the  $C^2MOS$  low power dissipation.

The TC7W53 has a 2 channel configuration.

The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ( $V_{CC} - V_{EE}$ ) can then be switched by the small logical amplitude ( $V_{CC} - GND$ ) control signal.

For example, in the case of V<sub>CC</sub> = 5 V, GND = 0 V, V<sub>EE</sub> = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with a signal power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuit with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features

- High speed:  $t_{pd} = 15$  ns (typ.) at  $V_{CC} = 5$  V,  $V_{EE} = 0$  V
- Low power dissipation:  $I_{CC} = 4 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Low ON resistance:  $RON = 50 \Omega$  (typ.) at VCC-VEE = 9 V
- High degree of linearity: THD = 0.02% (typ.) at V<sub>CC</sub>-V<sub>EE</sub> =9 V
- Pin and function compatible with TC4W53



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

#### Marking



Start of commercial production 1997-12

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
	V <sub>CC</sub>	–0.5 to 7	V	
Supply voltage range	$V_{CC} - V_{EE}$	–0.5 to 13	v	
Control input voltage	V <sub>IN</sub>	$-0.5$ to $V_{CC}$ + 0.5	V	
Switch I/O voltage	V <sub>I/O</sub>	$V_{EE}$ –0.5 to $V_{CC}$ + 0.5	V	
Control input diode current	ICK	±20	mA	
I/O diode current	IIOK	±20	mA	
Switch through current	Ι <sub>Τ</sub>	±25	mA	
DC V <sub>CC</sub> /GND current	Icc	±25	mA	
Power discipation	D-	300 (SM8)	mW	
	гD	200 (US8)		
Storage temperature range	T <sub>stg</sub>	-65 to 150	°C	
Lead temperature (10 s)	TL	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Truth Table**

Contro	ol Input	On Channel
INH	А	On Channel
L	L	Ch 0
L	Н	Ch 1
Н	Х	None

X: Don't care

#### Logic Symbol



#### Pin Assignment (top view)



## TOSHIBA Logic Diagram



#### **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
	V <sub>CC</sub>	2 to 6		
Supply voltage	V <sub>EE</sub>	-6 to 0	V	
	$V_{CC} - V_{EE}$	2 to 12		
Control input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Switch I/O voltage	V <sub>I/O</sub>	V <sub>EE</sub> to V <sub>CC</sub>	V	
Operating temperature range	T <sub>opr</sub>	-40 to 85	°C	
		0 to 1000 (V <sub>CC</sub> = 2.0 V)	ns	
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = $4.5$ V)		
		0 to 400 (V <sub>CC</sub> = 6.0 V)		

#### **Electrical Characteristics**

#### **DC Electrical Characteristics**

Characteristics S		Symbol Test Condition				Ta = 25°C			Ta =40 to 85°C		Unit
onaraota			$V_{\text{EE}}$ (V)	$V_{CC}(V)$	Min	Тур.	Max	Min	Max	Onit	
			_	2.0	1.5			1.5			
	High level	VIHC	—	_	4.5	3.15	_	_	3.15	_	V
Control input					6.0	4.2		_	4.2	_	
voltage					2.0			0.5		0.5	
	Low level	V <sub>ILC</sub>			4.5			1.35		1.35	
					6.0		—	1.8	—	1.8	
			VIN = VILC OF VINC	GND	4.5		85	180	—	225	
			$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5		55	120		150	Ω
			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		50	100	_	125	
ON resistance		R <sub>ON</sub>		GND	2.0		150	_	—	_	
		V V I <sub>I</sub> /	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$ $V_{I/O} = V_{CC} \text{ or } V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	GND	4.5		70	150	—	190	
				-4.5	4.5	_	50	100	—	125	
			-6.0	6.0	_	45	80	—	100		
Difference of C	N	$\Delta R_{ON} \begin{array}{c} V_{IN} = V_{ILC} \text{ or } V_{IHC} \\ V_{I/O} = V_{CC} \text{ to } V_{EE} \\ I_{I/O} \leq 2 \text{ mA} \end{array}$	GND	4.5	_	10	30	—	35		
resistance betw	veen		$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5		5	12	—	15	Ω
switches			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0		5	10		12	
Input/output lea	akage	$I_{OFF}  \begin{array}{l} V_{OS} = V_{CC} \text{ or } GND \\ V_{IS} = GND \text{ to } V_{CC} \\ V_{IN} = V_{ILC} \text{ or } V_{IHC} \end{array}$	GND	6.0		_	±60	_	±600	~^	
current (switch	off)		$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	_	±100	_	±1000	ΠA
Switch input lea	akage	L	$V_{OS} = V_{CC}$ or GND	GND	6.0	_	_	±60	_	±600	20
(switch on output open)	ηZ	$V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0		_	±100	_	±1000	ΠA	
Control input c	urrent	I <sub>IN</sub>	$V_{IN} = V_{CC} \text{ or } GND$	GND	6.0	_	_	±0.1	—	±1.0	μA
Outoosont	alv aureat	1.		GND	6.0			4		40	
Quiescent supply current	ICC	$I_{CC}$ $V_{IN} = V_{CC}$ or GND	-6.0	6.0			8	—	80	μA	

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
	Cymbol	Test condition	$V_{EE}(V)$	$V_{CC}\left(V\right)$	Min	Тур.	Max	Min	Max	onit
			GND	2.0	_	25	60	_	75	ns
Phase difference between		_	GND	4.5		6	12	_	15	
input and output	φι/Ο		GND	6.0	_	5	10	_	13	
			-4.5	4.5		4				
			GND	2.0		50	225		280	
Output analytic time	t <sub>n71</sub>	R <sub>L</sub> = 1 kΩ	GND	4.5	_	14	45	_	56	ns
Output enable time	t <sub>pZH</sub>		GND	6.0	_	12	38	_	48	
			-4.5	4.5	_	14	_	_	_	
	t <sub>pLZ</sub> t <sub>pHZ</sub>	R <sub>L</sub> = 1 kΩ	GND	2.0		95	225		280	ns
			GND	4.5		30	45	_	56	
Output disable time			GND	6.0		26	38	_	48	
			-4.5	4.5	_	26	_	_	_	
Control input capacitance	C <sub>IN</sub>	—	_	_	_	5	10	_	10	pF
Common terminal capacitance	C <sub>IS</sub>	—	-5.0	5.0	_	11	20		20	pF
Switch terminal capacitance	C <sub>OS</sub>	—	-5.0	5.0	_	7	15		15	pF
Feed through capacitance	C <sub>IOS</sub>		-5.0	5.0	_	0.75	2	_	2	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note)	GND	5.0	_	67	_	_	_	pF

#### AC Electrical Characteristics (C<sub>L</sub> = 50 pF, input $t_r = t_f = 6 \text{ ns}$ , GND = 0 V)

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:  $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 

#### Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

Characteristics	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Тур.	Unit		
			V <sub>IN</sub> = 4.0 Vp-p		-2.25	-2.25	0.025	
Sine wave distortion (T.H.D)	_	$\label{eq:RL} \begin{split} R_L &= 10 \; k\Omega, \; C_L = 50 \; pF \\ f_{IN} &= 1 \; kHz \end{split}$	V <sub>IN</sub> =	V <sub>IN</sub> = 8.0 Vp-p		4.5	0.02	%
(			V <sub>IN</sub> =	V <sub>IN</sub> = 11 Vp-p		6.0	0.018	
			(Note1)			2.5	120	
				(Note2)	-2.20	-2.5	95	
Frequency response		Adjust V <sub>IN</sub> voltage to obtain 0dBm at v Increase F <sub>IN</sub> until dB Meter reads –3d	√ <sub>OS</sub> IB	(Note1)	4.5		190	
(switch ON)	τ <sub>ΜΑΧ</sub>	$R_L = 50 \Omega$ , $C_L = 10 pF$ $f_{IN} = 1 MHz$ , sine wave		(Note2)	-4.5	4.5	150	MHZ
				(Note1)			200	
		(Note:			-6.0	6.0	190	
		Visits centered at (Voo-Vcc)/2 Adjus	st input f	for 0dBm	-2.25	2.25	-50	
Feed Through attenuation (switch OFF)	_	$R_L = 600 \Omega$ , $C_L = 50 \text{ pF}$ $f_{IN} = 1 \text{ MHz}$ , sine wave			-4.5	-4.5	-50 -50	dB
(0					-6.0	6.0		
Crosstalk			-2.25 2.	2.25	60			
(control input to signal	_	$R_L = 600 \Omega$ , $C_L = 50 pF$ fin = 1 MHz square wave ( $t_r = t_f = 6 n$	(2)		-4.5	-4.5 -4.5	140	mV
output)		$r_{\rm IIN} = 1$ (10112, square wave ( $t_{\rm I} = t_{\rm I} = 0.05$ )			-6.0	6.0	200	
		Adjust $V_{IN}$ to obtain 0dBm at input $R_L = 600 \ \Omega$ , $C_L = 50 \ pF$ $f_{IN} = 1 \ MHz$ , sine wave			2.25	2.25	-50	
Crosstalk (between any switches)	_				-4.5	-4.5 -4.5	-50	dB
					6.0	6.0	-50	

Note: These characteristics are determined by design of device.

Note 1: Input COMMON terminal, and measure at SWITCH terminal.

Note 2: Input SWITCH terminal, and measure at COMMON terminal.

#### **Switching Characteristics Test Circuits**

1.  $t_{pLZ}$ ,  $t_{pHZ}$ ,  $t_{pZL}$  and  $t_{pZH}$ 





2. Cross Talk (control input-switch output)  $f_{IN} = 1$  MHz, duty = 50% and  $t_r = t_f = 6$  ns



3. Feed Through Attenuation



# 4. C<sub>IOS</sub>, C<sub>IS</sub>, C<sub>OS</sub>



5. Cross Talk (between any two switches)



6. Frequency Response (switch ON)



## **TOSHIBA**

#### Package Dimensions

SSOP8-P-0.65

Unit : mm





Weight: 0.02 g (typ.)

#### **Package Dimensions**

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

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